

# UNISONIC TECHNOLOGIES CO., LTD

## MPSA113

## NPN EPITAXIAL SILICON TRANSISTOR

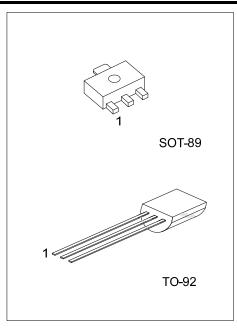
# DARLINGTON TRANSISTOR

#### DESCRIPTION

The UTC **MPSA113** is a Darlington transistor.

#### FEATURES

\* Collector-Emitter Voltage: V<sub>CES</sub> = 30V



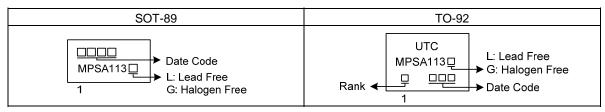
#### ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignment			Dealing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MPSA113L-AB3-R	MPSA113G-AB3-R	SOT-89	В	С	Е	Tape Reel	
MPSA113L-T92-B	MPSA113G-T92-B	TO-92	Е	В	С	Tape Box	
MPSA113L-T92-K	MPSA113G-T92-K	TO-92	Е	В	С	Bulk	
Noto: Din Assignment: P: Pase C: Collector E: Emitter							

Note: Pin Assignment: B: Base C: Collector E: Emitter

MPSA113G-AB3-R	
T (1)Packing Type	(1) B: Tape Box, K: Bulk, R: Tape Reel
(2)Package Type	(2) AB3: SOT-89, T92: TO-92
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

#### MARKING



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#### ABSOLUTE MAXIMUM RATING (Operating temperature range applies unless otherwise specified.)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V <sub>CBO</sub> 30		V
Collector-Emitter Voltage	V <sub>CES</sub> 30		V
Emitter-Base Voltage	V <sub>EBO</sub>	10	V
Collector Dissipation(Tc=25°C)	P <sub>C</sub> 625		mW
Collector Current	Ι <sub>C</sub>	500	mA
Junction Temperature	TJ	+150	٥C
Storage Temperature	T <sub>STG</sub>	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ELECTRICAL CHARACTERISTICS (TJ=25°C, unless otherwise specified)

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	I <sub>C</sub> =100μA, I <sub>B</sub> =0	30			V
Collector Cut-Off Current	I <sub>CBO</sub>	$V_{CB}=30V, I_{E}=0$			100	nA
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>EB</sub> =10V, I <sub>C</sub> =0			100	nA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>c</sub> =100mA	30000			
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =0.1mA			1.5	V
Base-Emitter on Voltage	V <sub>BE(ON)</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =100mA			2.0	V
Current Gain Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =5V,I <sub>C</sub> =10mA, f=100MHz	125			MHz

Note: Pulse test: Pulse Width<300µs, Duty Cycle=2%



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